MCH3377



http://onsemi.com

P-Channel Power MOSFET -20V, -3A, 83mΩ, Single MCPH3

Features

- · Ultrahigh-spees switching.
- · Halogen free compliance

- · 1.8V drive
- · Protection diode in

Specifications

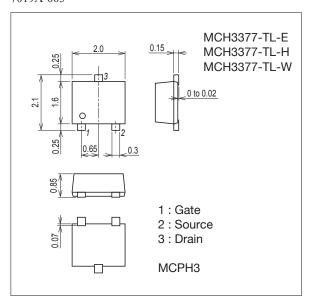
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		-20	V
Gate-to-Source Voltage	VGSS		±10	V
Drain Current (DC)	ID		-3	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-12	А
Allowable Power Dissipation	PD	When mounted on ceramic substrate (900mm ² ×0.8mm)	1	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Package Dimensions

unit: mm (typ) 7019A-003

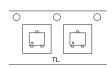


Product & Package Information

• Package : MCPH3

• JEITA, JEDEC : SC-70, SOT-323 • Minimum Packing Quantity : 3,000 pcs./reel

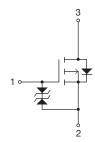
Packing Type: TL



Marking



Electrical Connection



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

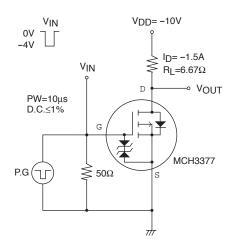
MCH3377

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
		Conditions	min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =-1mA, V _G S=0V	-20			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-20V, V _{GS} =0V			-1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	V _{GS} (off)	V _{DS} =-10V, I _D =-1mA	V _{DS} =-10V, I _D =-1mA -0.4		-1.3	V
Forward Transfer Admittance	yfs	V _{DS} =-10V, I _D =-1.5A	2.2	3.8		S
Static Drain-to-Source On-State Resistance	RDS(on)1	I _D =-1.5A, V _G S=-4.5V		63	83	mΩ
	R _{DS} (on)2	I _D =-1A, V _G S=-2.5V		88	125	mΩ
	R _{DS} (on)3	I _D =-0.2A, V _G S=-1.8V		130	200	mΩ
Input Capacitance	Ciss	V _{DS} =-10V, f=1MHz		375		pF
Output Capacitance	Coss			77		pF
Reverse Transfer Capacitance	Crss	1		58		pF
Turn-ON Delay Time	t _d (on)			8.1		ns
Rise Time	t _r	Construction of Total Circuit		26		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		42		ns
Fall Time	tf	1		37		ns
Total Gate Charge	Qg			4.6		nC
Gate-to-Source Charge	Qgs	V _{DS} =-10V, V _{GS} =-4.5V, I _D =-3A		0.8		nC
Gate-to-Drain "Miller" Charge	Qgd	1		1.3		nC
Diode Forward Voltage	V _{SD}	I _S =-3A, V _{GS} =0V		-0.83	-1.2	V

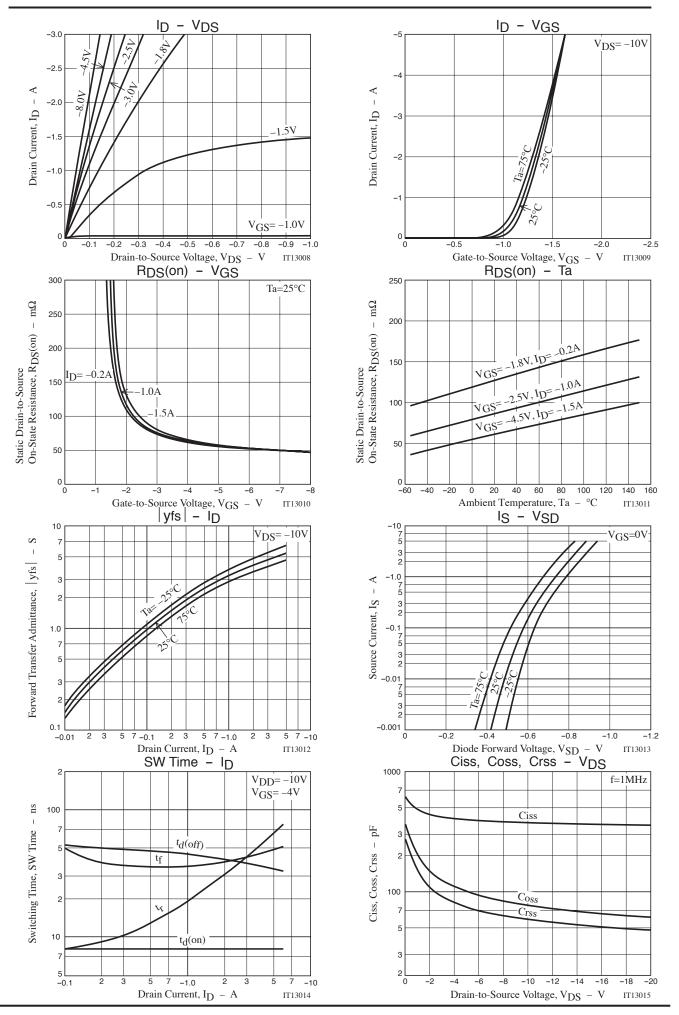
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

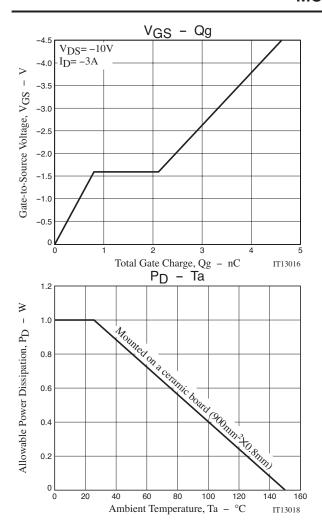
Switching Time Test Circuit

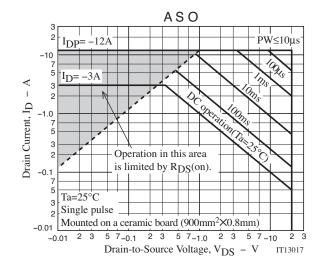


Ordering Information

Device	Package	Shipping	memo	
MCH3377-TL-E			Pb-Free	
MCH3377-TL-H	МСРН3	3,000pcs./reel	Pb-Free and Halogen Free	
MCH3377-TL-W			Pb-Free and Halogen Free	



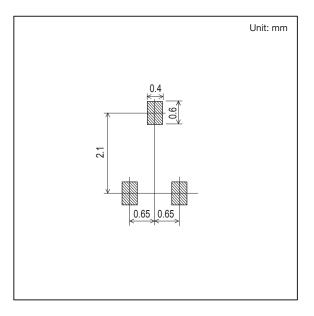




Outline Drawing

MCH3377-TL-E, MCH3377-TL-H, MCH3377-TL-W

Land Pattern Example



Note on usage: Since the MCH3377 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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